

Product Summary

BV _{DSS}	Rds(on) Max	Qg Typ	I _D Tc = +25°C (Note 9)
40V	3.2mΩ @ V _{GS} = 10V	68.6nC	100A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Engine management systems
- Body control electronics
- DC/DC converters

Features

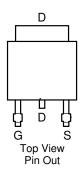
- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application
- Low RDS(ON) Minimizes Power Losses
- Low Qg Minimizes Switching Losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DIODES™ DMTH4004SK3Q is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

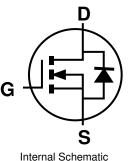
https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: TO252
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.33 grams (Approximate)







Ordering Information (Note 4)

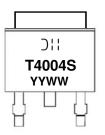
Part Number	Package	Packing		
Part Number	Package	Qty.	Carrier	
DMTH4004SK3Q-13	TO252 (DPAK)	2,500	Tape & Reel	

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



DII =Manufacturer's Marking T4004S = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 22 = 2022) WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	VDSS	40	V		
Gate-Source Voltage	V _{GSS}	±20	V		
Continuous Drain Current (Note 6)	Tc = +25°C (Note 9)	ID	100	А	
, , , , , , , , , , , , , , , , , , ,	Tc = +100°C		100	1	
Maximum Body Diode Forward Current (Note 6)		ls	100	A	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	160	A		
Avalanche Current, L=0.2mH	las	40	A		
Avalanche Energy, L=0.2mH	Eas	160	mJ		

Thermal Characteristics

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	TA = +25°C	PD	3.9	W
Thermal Resistance, Junction to Ambient (Note 5)	R _{θJA}	38	°C/W	
Total Power Dissipation (Note 6) $T_{C} = +25^{\circ}C$		PD	180	W
Thermal Resistance, Junction to Case (Note 6)		Rejc	0.8	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +175	°C	

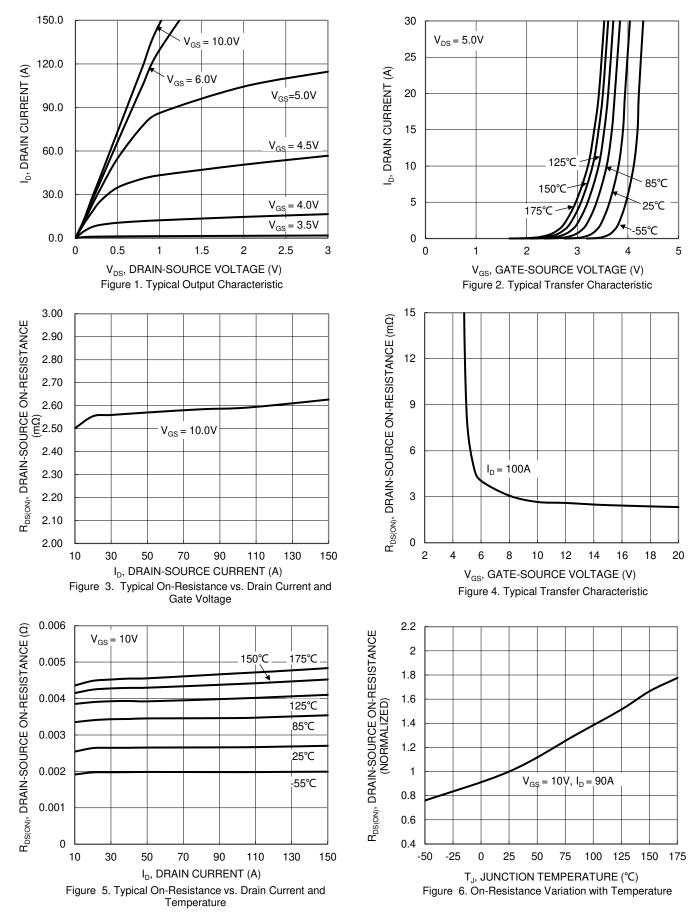
Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	40			V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	IDSS			1	μA	$V_{DS} = 32V, V_{GS} = 0V$	
Gate-Source Leakage	lgss	_		±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	VGS(TH)	2		4	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	RDS(ON)		2.6	3.2	mΩ	VGS = 10V, ID = 90A	
Diode Forward Voltage	Vsd		0.9	1.2	V	V _{GS} = 0V, I _S = 20A	
DYNAMIC CHARACTERISTICS (Note 8)	DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss		4,305		pF	V _{DS} = 25V, V _{GS} = 0V, f = 1MHz	
Output Capacitance	Coss		1,441				
Reverse Transfer Capacitance	Crss	_	102				
Gate Resistance	Rg		0.77		Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge	Qg	_	68.6			$\label{eq:VDS} \begin{array}{l} V_{DS} = 20V, \ I_D = 90A, \\ V_{GS} = 10V \end{array}$	
Gate-Source Charge	Qgs	_	16.8		nC		
Gate-Drain Charge	Q _{gd}	_	14.2				
Turn-On Delay Time	t _{D(ON)}		9.5				
Turn-On Rise Time	tR		6.7		ns	$\label{eq:VDD} \begin{split} V_{DD} &= 20V, \ V_{GS} = 10V, \\ I_D &= 90A, \ R_G = 3.5\Omega \end{split}$	
Turn-Off Delay Time	t _{D(OFF)}		26.4		115		
Turn-Off Fall Time	tF		8.1				
Body Diode Reverse Recovery Time	trr		52.4	_	ns	L 500 di/dt 1000/up	
Body Diode Reverse Recovery Charge	Qrr		78.2		nC	-I _F = 50A, di/dt = 100A/μs	

Notes: 5. Device mounted with exposed drain pad on 25mm by 25mm 2oz copper on a single- sided 1.6mm FR-4 PCB; device is measured under still air conditions bevice mounted with exposed train pad on 25mm by 25mm 202 copper on whilst operating in a steady state.
Thermal resistance from junction to solder point (on the exposed drain pin).
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to production testing.
Package limited.



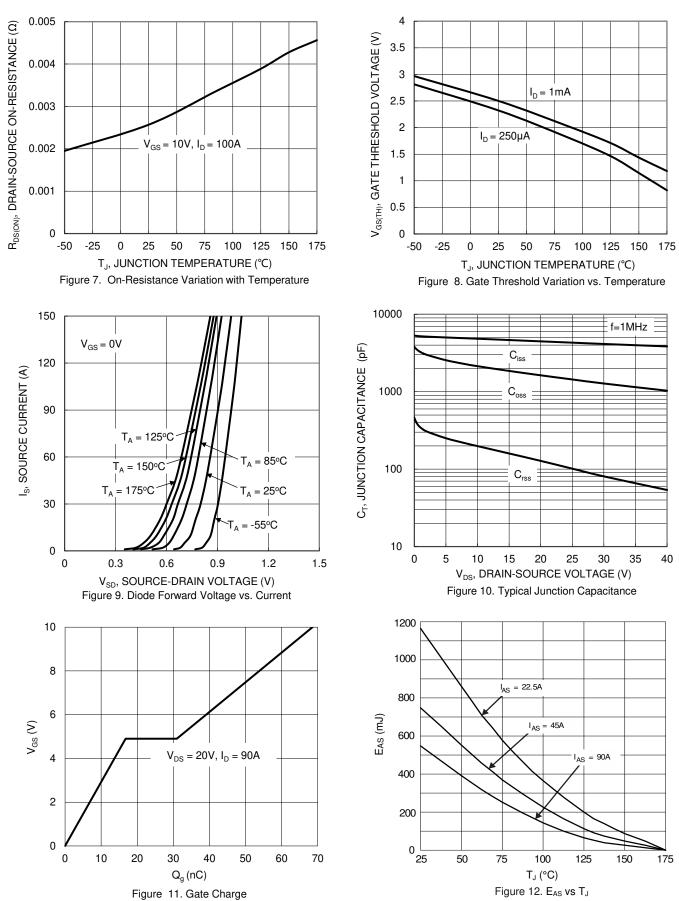
DMTH4004SK3Q



DMTH4004SK3Q Document number: DS38660 Rev. 3 - 2

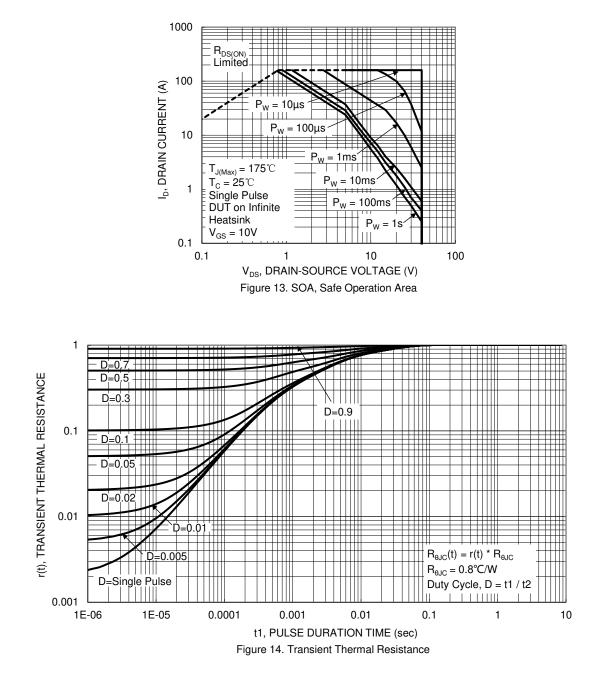


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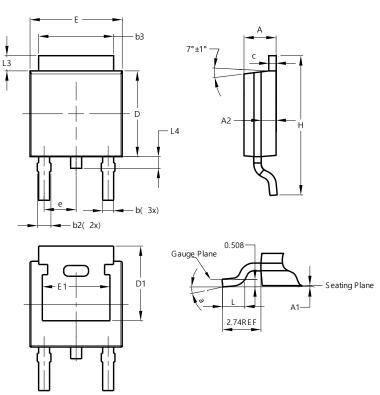




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Package Outline Dimensions

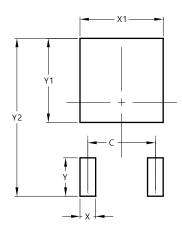
Please see http://www.diodes.com/package-outlines.html for the latest version.



TO252 (DPAK)					
Dim	Min	Max	Тур		
Α	2.19	2.39	2.29		
A1	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
b	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b3	5.21	5.50	5.33		
С	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	5.21				
е	2.286 BSC				
Е	6.45	6.70	6.58		
E1	4.32				
Ξ	9.40	10.41	9.91		
L	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.64	1.02	0.83		
а	0°	10°			
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



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Dimensions	Value (in mm)
С	4.572
Х	1.060
X1	5.632
Y	2.600
Y1	5.700
Y2	10.700

TO252 (DPAK)

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